



SO8



TO52



TO220



TO237



TO92 (2 lead)



TO92 (3 lead)

Low-Power Discrettes

DMOS FETs – Low-Power MOS N-Channel Enhancement-Mode

Part Number	$V_{(BR)DSS}$ Min (V)	$r_{DS(on)}$ Max (Ω)	$V_{GS(St)}$ Max (V)	t_{ON} Max (ns)	C_{iss} Typ (pF)	I_p Max (A)	P_D Max (W)
14-Pin Sidebrazed (P) and Plastic (J)							
VQ1001J	30	1	2.5	30	38	3	2
VQ1001P		1	2.5	30	38	3	2
VQ1004J	60	3.5	2.5	10	35	0.46	1.3
VQ1004P		3.5	2.5	10	35	0.46	1.3
VQ1000J		5.5	2.5	10	22	1	1.3
VQ1000P		5.5	2.5	10	22	1	1.3
VQ1006P	90	4.5	2.5	10	35	2	2
TO236 (SOT23)							
TN0200T	20	0.4	1.0 (typ)	34	90	4.0	0.23
TN0201T		1	3.0	15 (typ)	65	0.75	0.2
VN0605T	60	5	3.0	20	22	0.72	0.36
2N7002		7.5	2.5	20	22	0.8	0.2
TN2010T	200	11	3.0	20 (typ)	35	0.085	0.2
TN2460T	240	60	1.8	20	14	0.4	0.36
VN50300T	500	300	4.5	20	5	0.08	0.35
TO205AD (TO39)							
2N6659	35	1.8	2	10	35	3	6.25
2N6660JANTX	60	3	2	10	35	3	6.25
2N6660		3	2	10	35	3	6.25
2N6661JANTX	90	4	2	10	35	3	6.25
2N6661		4	2	10	35	3	6.25
TO206AD (TO52)							
VN10LE	60	5	2.5	10	22	1	1.5
VN10KE		5	2.5	10	38	1	0.3
TO220/TO220SD							
VN66AFD	60	3	2.5	15	35	3	15
VN88AFD	80	4	2.5	15	35	3	15
VN2406D	240	6	2.0	16	110	3	20
TO237							
VN0300M	30	1.2	2.5	30	38	3	1
VN0606M		3	2.0	10	35	2	1
VN10KM	60	5	2.5	10	38	1	1
VN10LM		5	2.5	10	22	1.4	1
VN2222LM		7.5	2.5	10	22	1	1
VN0808M	80	4	2.0	10	35	1.9	1
VN1206M	120	6	2.0	16	35	2	1
VN1210M		10	2.0	16	35	2	1
VN2406M	240	6	2.0	16	110	2	1
VN2410M		10	2.0	16	110	2	1
TO226AA (TO92)							
TN0201L	20	1.2	2.0	30	38	1.5	0.8
VN0300L	30	1.2	2.5	30	38	3	0.8